Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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2SK3233

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1096-0200

(Previous: ADE-208-1369)

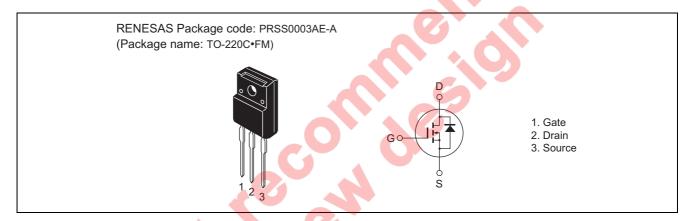
Rev.2.00

Sep 07, 2005

Features

- Low on-resistance: $R_{DS (on)} = 1.1 \Omega$ typ.
- Low leakage current: $I_{DSS} = 1 \mu A \text{ max (at } V_{DS} = 500 \text{ V})$
- High speed switching: $t_f = 15$ ns typ (at $V_{GS} = 10$ V, $V_{DD} = 250$ V, $I_D = 2.5$ A)
- Low gate charge: Qg = 15 nC typ (at $V_{DD} = 400 \text{ V}$, $V_{GS} = 10 \text{ V}$, $I_D = 5 \text{ A}$)
- Avalanche ratings

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	500	V
Gate to source voltage	V _{GSS}	±30	V
Drain current	I _D	5	A
Drain peak current	I _{D (pulse)} Note 1	20	A
Body-drain diode reverse drain current	I _{DR}	5	A
Body-drain diode reverse drain peak current	I _{DR} (pulse) Note 1	20	A
Avalanche current	I _{AP} Note 3	5	A
Channel dissipation	Pch Note 2	30	W
Channel to case thermal impedance	θ ch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

3. Tch ≤ 150°C

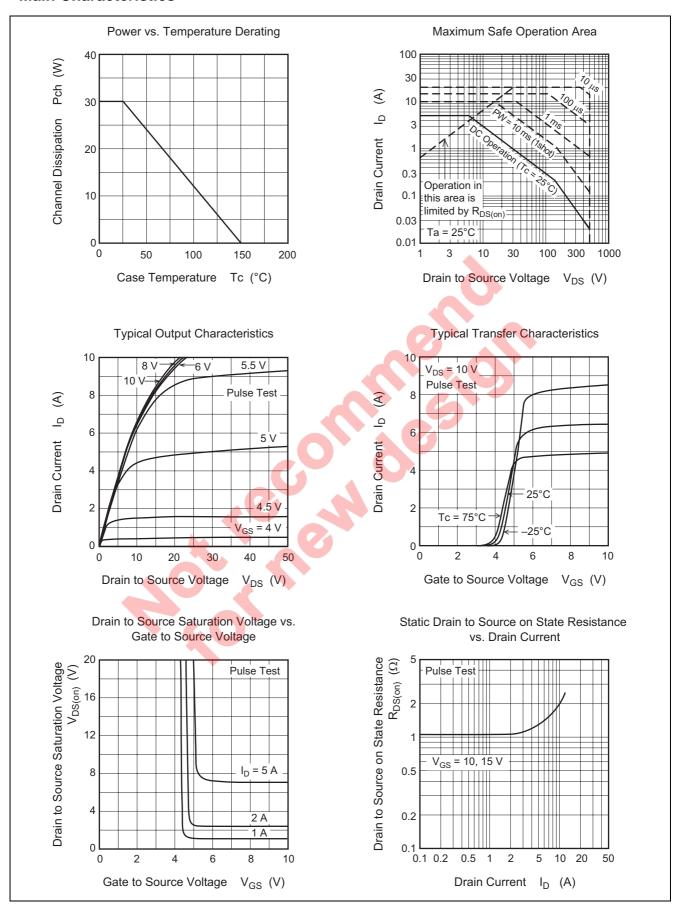
Electrical Characteristics

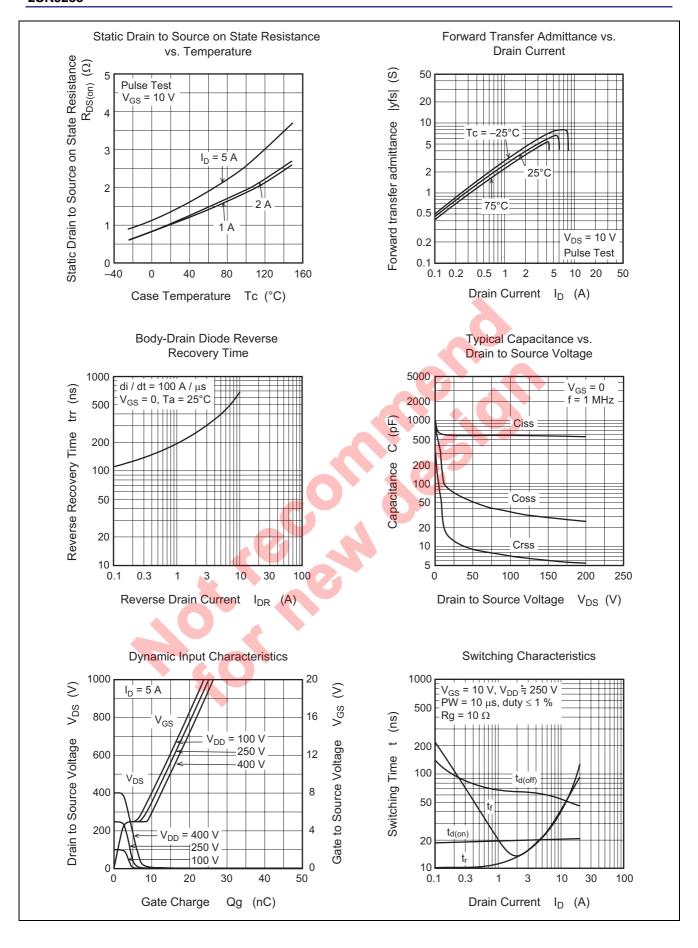
 $(Ta = 25^{\circ}C)$

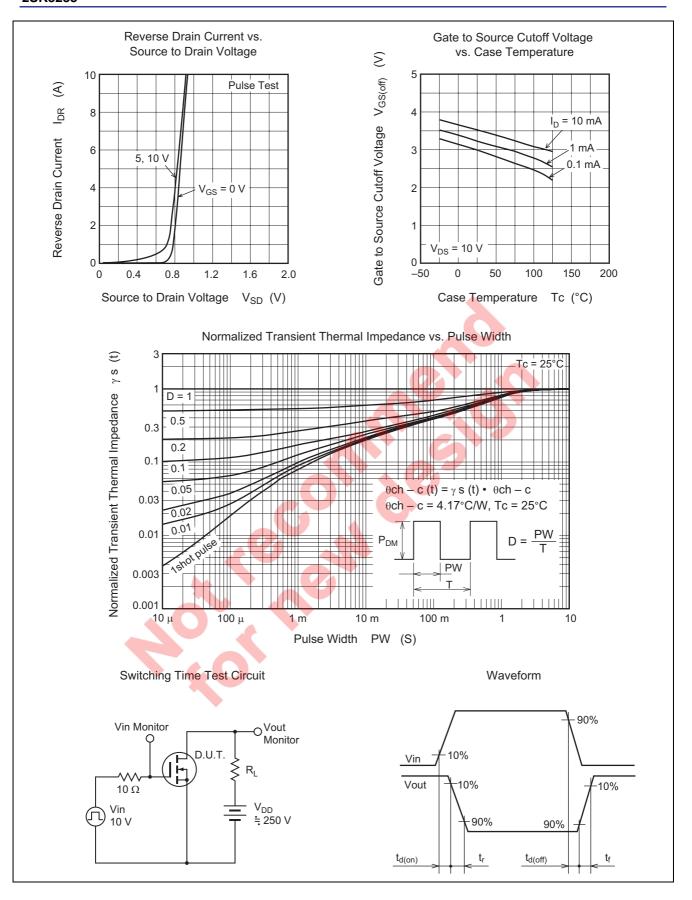
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	500		7	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	1	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}			1	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	3.0		4.0	٧	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	R _{DS} (on)	_	1.1	1.5	Ω	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y _{fs}	3.0	4.5	_	S	$I_D = 2.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	47	580	_	pF	V _{DS} = 25 V
Output capacitance	Coss		70	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	13	_	pF	f = 1 MHz
Turn-on delay time	t _{d (on)}	_	20	_	ns	I _D = 2.5 A
Rise time	t_{r}	_	15		ns	V _{GS} = 10 V
Turn-off delay time	t _{d (off)}	_	65	_	ns	$R_L = 100 \Omega$
Fall time	t _f	_	15	_	ns	$Rg = 10 \Omega$
Total gate charge	Qg		15		nC	V _{DD} = 400 V
Gate to source charge	Qgs	_	3	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	8	_	nC	$I_D = 5 A$
Body-drain diode forward voltage	V_{DF}	_	0.85	1.3	V	$I_F = 5 A, V_{GS} = 0$
Body-drain diode reverse recovery time	t _{rr}	_	400	_	ns	$I_F = 5 \text{ A}, V_{GS} = 0$
Body-drain diode reverse recovery charge	Q _{rr}		1.5	_	μС	di _F /dt = 100 A/μs

Note: 4. Pulse test

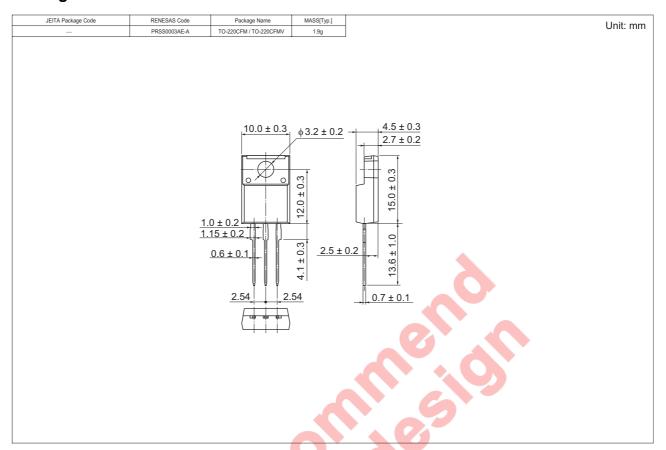
Main Characteristics







Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SK3233-E	600 pcs	Box (Tube)

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